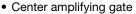


Phase Control Thyristors (Stud Version), 280 A



PRODUCT SUMMARY			
I _{T(AV)}	280 A		
V _{DRM} /V _{RRM}	400 V, 600 V		
V_{TM}	1.28 V		
I _{GT}	150 mA		
T _J	-40 °C to +125 °C		
Package	TO-93 (TO-209AB)		
Circuit configuration	Single SCR		

FEATURES





• International standard case TO-93 (TO-209AB)

Hermetic metal case with glass-metal seal

RoHS COMPLIANT

- insulator
- Compression bonded encapsulation for heavy duty operations such as severe thermal cycling
- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

- DC motor controls
- Controlled DC power supplies
- AC controllers

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST CONDITIONS	VALUES	UNITS	
1		280	A	
I _{T(AV)}	T _C	85	°C	
I _{T(RMS)}		440		
I _{TSM}	50 Hz	7850	A	
	60 Hz	8220		
12.	50 Hz	308	kA ² s	
l ² t	60 Hz	281	KA-S	
V _{DRM} /V _{RRM}		400/600	V	
t _q	Typical	100	μs	
T _J		-40 to +125	°C	

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS								
TYPE NUMBER	BER VOLTAGE CODE VDRM/VRRM, MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V		V _{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	I_{DRM}/I_{RRM} MAXIMUM AT $T_J = T_J$ MAXIMUM mA				
VS-ST280S	04	400	500	30				
V3-312003	06	600	700	30				



ABSOLUTE MAXIMUM RATINGS	S					
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS
Maximum average on-state current	L	180° condu	ction, half sine v	wave	280	Α
at case temperature	$I_{T(AV)}$				85	°C
Maximum RMS on-state current	I _{T(RMS)}	DC at 75 °C	case temperat	ure	440	
		t = 10 ms	No voltage		7850	
Maximum peak, one-cycle	L	t = 8.3 ms	reapplied		8220	A
non-repetitive surge current	I _{TSM}	t = 10 ms	100 % V _{RRM}	Sinusoidal half wave,	6600	
		t = 8.3 ms	reapplied		6900	
Maximum I ² t for fusing		t = 10 ms No voltage	initial $T_J = T_J$ maximum	310		
	l ² t	t = 8.3 ms	reapplied		220	kA ² s
		t = 10 ms	100 % V _{RRM}		218	
		t = 8.3 ms	reapplied		200	
Maximum I ² √t for fusing	I ² √t	t = 0.1 to 10) ms, no voltage	reapplied	3100	kA²√s
Low level value of threshold voltage	V _{T(TO)1}	(16.7 % x π	$x I_{T(AV)} < I < \pi x$	$I_{T(AV)}$), $T_J = T_J$ maximum	0.84	V
High level value of threshold voltage	V _{T(TO)2}	$(I > \pi \times I_{T(AV)})$	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$			V
Low level value of on-state slope resistance	r _{t1}	(16.7 % x π x $I_{T(AV)} < I < \pi$ x $I_{T(AV)}$), $T_J = T_J$ maximum			0.50	mΩ
High level value of on-state slope resistance	r _{t2}	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$			0.47	1115.2
Maximum on-state voltage	V_{TM}	$I_{pk} = 880 \text{ A}, T_J = T_J \text{ maximum}, t_p = 10 \text{ ms sine pulse}$		1.28	V	
Maximum holding current	I _H	T 05:00 1 10V 111 1		2 V registive lead	600	mΛ
Maximum (typical) latching current	ΙL	T _J = 25 °C, anode supply 12 V resistive load			1000 (300)	mA

SWITCHING						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum non-repetitive rate of rise of turned-on current	dl/dt	Gate drive 20 V, 20 Ω , $t_r \le 1~\mu s$ $T_J = T_J$ maximum, anode voltage $\le 80~\%~V_{DRM}$	1000	A/µs		
Typical delay time	t _d	Gate current 1 A, $dl_g/dt = 1 A/\mu s$ $V_d = 0.67 \% V_{DRM}, T_J = 25 °C$	1.0			
Typical turn-off time	t _q	I_{TM} = 300 A, T_J = T_J maximum, dI/dt = 20 A/ μ s, V_R = 50 V, dV/dt = 20 V/ μ s, gate 0 V 100 Ω , t_p = 500 μ s	100	μs		

BLOCKING							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNIT S			
Maximum critical rate of rise of off-state voltage	dV/dt	T _J = T _J maximum linear to 80 % rated V _{DRM}	500	V/µs			
Maximum peak reverse and off-state leakage current	I _{RRM,} I _{DRM}	$T_J = T_J$ maximum, rated V_{DRM}/V_{RRM} applied	30	mA			



TRIGGERING						
PARAMETER	SYMBOL		TTOT COMPLETIONS		VALUES	
PARAMETER	STIVIBUL	TEST CONDITIONS		TYP.	MAX.	S
Maximum peak gate power	P_{GM}	$T_J = T_J$ maximum,	, t _p ≤ 5 ms	10	0.0	W
Maximum average gate power	P _{G(AV)}	$T_J = T_J$ maximum,	, f = 50 Hz, d% = 50	2	.0	VV
Maximum peak positive gate current	I _{GM}	$T_J = T_J$ maximum,	, t _p ≤ 5 ms	3	.0	Α
Maximum peak positive gate voltage	+ V _{GM}	$T_{J} = T_{J}$ maximum, $t_{p} \le 5$ ms		2	.0	V
Maximum peak negative gate voltage	- V _{GM}			5.0]
		T _J = - 40 °C	Maximum required gate trigger/current/voltage are the lowest value which will	180	-	mA
DC gate current required to trigger	I_{GT}	T _J = 25 °C		90	150	
		T _J = 125 °C		40	-	
		T _J = - 40 °C	trigger all units 12 V anode to cathode	2.9	1	
DC gate voltage required to trigger	V_{GT}	T _J = 25 °C	applied	1.8	3.0	V
		T _J = 125 °C			-	
DC gate current not to trigger	I _{GD}	T T. movimum	Maximum gate current/voltage not to trigger is the maximum value which will	-	0	mA
DC gate voltage not to trigger	V_{GD}	$ T_{J} = T_{J} \text{ maximum} $ $ \text{not trigger any unit with rated } V_{DRM} $ $ \text{anode to cathode applied} $		0.	25	V

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum operating junction temperature range	TJ		-40 to +125	°C	
Maximum storage temperature range	T _{Stg}		-40 to +150	°C	
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	0.105 K/W		
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased			
Maunting targue + 10 0/		Non-lubricated threads	31 (275)	N·m	
Mounting torque, ± 10 %		Lubricated threads	24.5 (210)	(lbf · in)	
Approximate weight			280	g	
Case style		See dimensions - link at the end of datasheet	TO-93 (TO-	209AB)	

△R _{thJC} CONDUCTION						
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS		
180°	0.016	0.012				
120°	0.019	0.020				
90°	0.025	0.027	$T_J = T_J$ maximum	K/W		
60°	0.036	0.037				
30°	0.060	0.060				

Note

• The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC



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Vishay Semiconductors

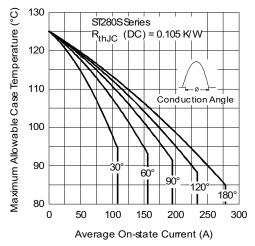


Fig. 1 - Current Ratings Characteristics

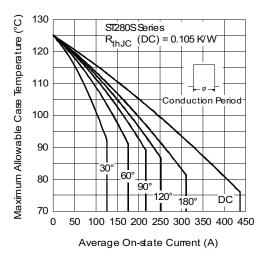


Fig. 2 - Current Ratings Characteristics

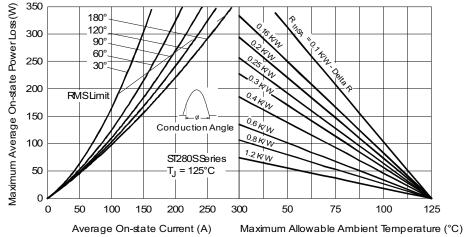


Fig. 3 - On-State Power Loss Characteristics

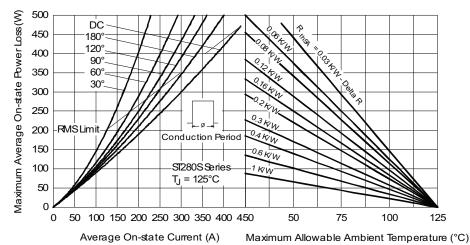


Fig. 4 - On-State Power Loss Characteristics



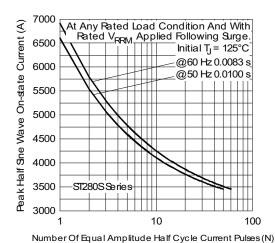
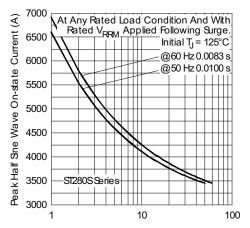


Fig. 5 - Maximum Non-Repetitive Surge Current



Number Of Equal Amplitude Half Cycle Current Pulses (N)



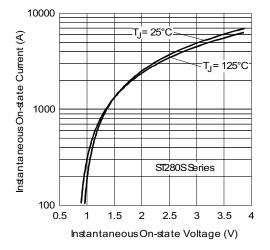


Fig. 7 - On-State Voltage Drop Characteristics

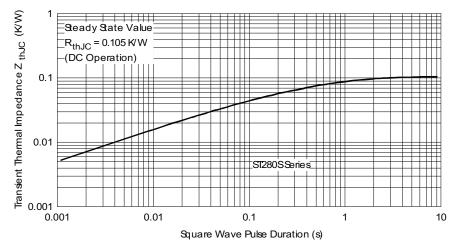


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

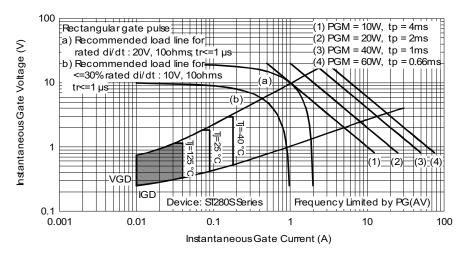
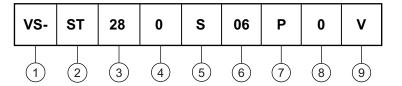


Fig. 9 - Gate Characteristics

ORDERING INFORMATION TABLE

Device code



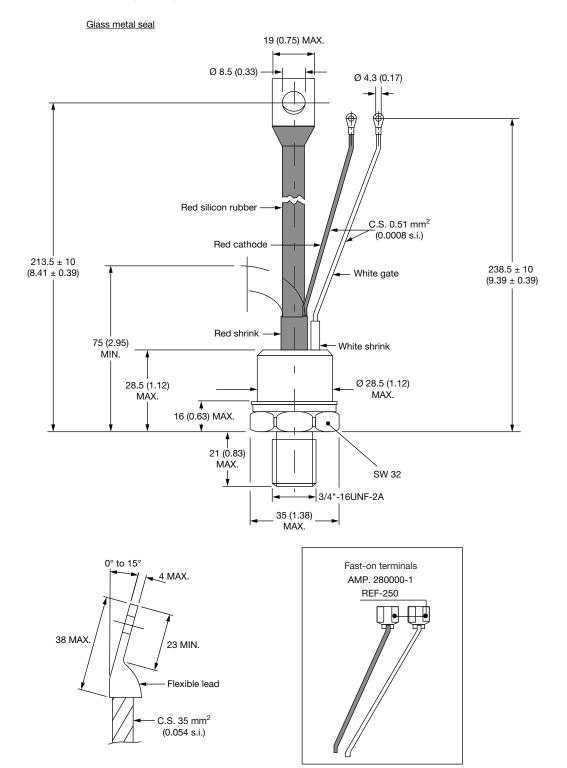
- 1 Vishay Semiconductors product
- 2 Thyristor
- 3 Essential part number
- 0 = converter grade
- 5 S = compression bonding stud
- 6 Voltage code x 100 = V_{RRM} (see Voltage Ratings table)
- P = stud base 3/4"-16UNF-2A threads
- 8 0 = eyelet terminals (gate and auxiliary cathode leads)
 - 1 = fast-on terminals (gate and auxiliary cathode leads)
- 9 V = glass-metal seal

LINKS TO RELATED DOCUMENTS		
Dimensions	www.vishay.com/doc?95077	



TO-209AB (TO-93)

DIMENSIONS in millimeters (inches)





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